TOSHIBA PHOTOINTERRUPTER INFRARED LED + PHOTO IC

TLP1000A, TLP1001A

HOME ELECTRIC EQUIPMENT SUCH AS VCR, CD PLAYER

OA EQUIPMENT SUCH AS COPYING MACHINE, PRINTER, FACSIMILE, ETC.

AUTOMATIC SERVICE EQUIPMENT SUCH AS VENDING MACHINE, TICKETING MACHINE, ETC.

VARIOUS POSITION DETECTION

TLP1000A and TLP1001A are digital output photointerrupters combining GaAs infrared LED with high sensitive and high gain Si photo IC.

Directly connectable to TTL, LSTTL and CMOS.

Both side mounting type

: 3mm Gap

Resolution : Slit width 1mm

Digital output (with a pull-up resistor)

TLP1000A: Low level output at shielding

TLP1001A: High level output at shielding

Built-in Schmitt-trigger circuit

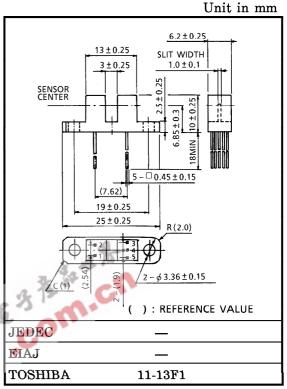
Threshold input current : 2.5mA (Max.) at

 $Ta = 25^{\circ}C$

Operating supply voltage : V_{CC}=4.5~17V

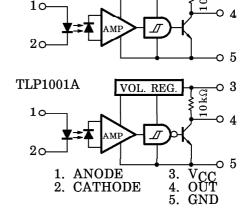
Fast response speed

Detector side is of visible light cut type.



Weight: 0.97g (Typ.) PIN CONNECTION

TLP1000A



VOL.

REG

961001EBC2

- TOSHIBA is continually working to improve the quality and the reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to observe standards of safety, and to avoid situations in which a malfunction or failure of a TOSHIBA product could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent products specifications. Also, please keep in mind the precautions and conditions set forth in the TOSHIBA Semiconductor Reliability Handbook.

 Gallium arsenide (GaAs) is a substance used in the products described in this document. GaAs dust and fumes are toxic. Do not break, cut or pulverize the product, or use chemicals to dissolve them. When disposing of the products, follow the appropriate regulations. Do not dispose of the products with other industrial waste or with domestic garbage.

 The products described in this document are subject to foreign exchange and foreign trade control laws.

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 The information contained herein is subject to change without notice.

MAXIMUM RATINGS (Ta = 25°C)

	CHARACTERISTIC	SYMBOL	RATING	UNIT	
	Forward Current	${f I_F}$	50	mA	
LED	Forward Current Derating (Ta>25°C)	$\Delta I_{\mathbf{F}} / {^{\circ}\mathbf{C}}$	-0.33	mA/°C	
	Reverse Voltage	$v_{ m R}$	5	V	
۲	Supply Voltage	v_{CC}	17	V	
rof	Output Current	IO	50	mA	
EC	Power Dissipation	PO	250	mW	
DETECTOR	Power Dissipation Derating (Ta>25°C)	ΔPO/°C	-3.33	mW/°C	
Op	erating Temperature Range	$T_{ m opr}$	-25~85	°C	
Storage Temperature Range		${f T}_{ m stg}$	-40~100	°C _4	
Soldering Temperature (5s)		T_{sol}	260	°C	

RECOMMENDED OPERATING CONDITIONS

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT
LED Forward Current	$I_{ m F}$	8.8*		20	mA
Supply Voltage	$v_{\rm CC}$	4.5	5.0	17	V
Low Level Output Current	$I_{ m OL}$	_	_	16	mA
Operating Temperature	$T_{ m opr}$	-25	1	85	$^{\circ}\mathrm{C}$

^{* 8.8}mA is a value when 50% LED deterioration is taken into consideration. Initial threshold input current shall be 4.4mA MAX.

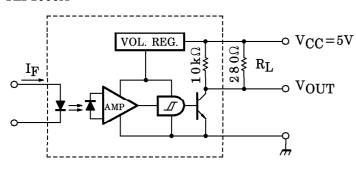
OPTO-ELECTRICAL CHARACTERISTICS (Unless otherwise specified, $Ta = -25 \sim 85$ °C, $V_{CC} = 5V \pm 10\%$)

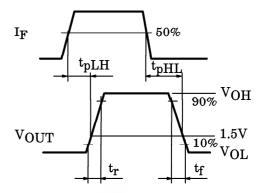
CHARACTERISTIC SYMBOL		TEST CONDITION		MIN.		MAX.	UNIT	
	Forward Voltage	$V_{\mathbf{F}}$	$I_F = 10$ mA, $T_a = 2$	1.00	1.15	1.30	V	
ĮΒ	Reverse Current	$I_{\mathbf{R}}$	$V_R = 5V, Ta = 25^\circ$	_	_	10	μ A	
	Reverse Current Peak Emission Wavelength	$\lambda_{\mathbf{P}}$	$I_{\mathbf{F}} = 15 \text{mA}, \text{ Ta} = 2$		940	_	nm	
	Supply Voltage	$v_{\rm CC}$		4.5	_	17	V	
	Low Level Supply	$ $ $_{\rm I_{CCL}}$	$I_{\mathbf{F}} = *1$	I _F =*1		_	6.0	mA
	Current	-CCL	$I_{F} = *1, V_{CC} = 17$	'V		_	7.5	mA
دم	High Level Supply	ICCH	$I_{\mathbf{F}} = *2$		_	3.0	mA	
OF	Current		$I_{F} = *2, V_{CC} = 17V$		_			3.2
DETECTOR	Low Level Output Voltage	V _{OL}	I_{OL} =16mA, I_{F} = Ta =25°C	_	0.07	0.3	\mathbf{v}	
			$I_{ m OL}$ =16mA, $I_{ m F}$ = $V_{ m CC}$ =17 V	*1	, t		0.4	V
	High Level Output Voltage	VOH	I _F =*2		0.9VCC	ı	_	V
	Peak Sensitivity Wavelength	$\lambda_{\mathbf{P}}$	Ta=25°C	CO	_	900	_	nm
	L→H Threshold Input Current	I _{FLH}	$Ta = 25^{\circ}C$	TLP1000A		_	2.5	mA
			$V_{\rm CC} = 17V$	TLI TOUCK	_	_	4.4	шА
	H→L Threshold Input	I _{FHL}	Ta = 25°C	TLP1001A	_	_	2.5	mA
	Current	-FIID	$V_{CC} = 17V$	1111100174		_	4.4	11171
	Hysteresis Ratio	I _{FHL} /I _{FLH}	_	TLP1000A	-	0.67	—	
Ω				TLP1001A	_	1.5	_	
PL	Propagation Delay Time (L→H)	t _{pLH}		TLP1000A	_	3	<u> </u>	
COUPLED			$V_{CC}=5V$ $I_{F}=15\text{mA}$ $R_{L}=280\Omega$	TLP1001A	_	6		
	Propagation Delay Time (H→L)	t _{pHL}		TLP1000A	_	6		μ s
			$\overline{\mathrm{Ta}} = 25^{\circ}\mathrm{C}$	TLP1001A	_	3	_	
	Rise Time	$\mathbf{t_r}$	(Note)		_	0.1	_	-
	Fall Time	t_f			_	0.05	_	

^{*1} TLP1000A=0, TLP1001A=15mA *2 TLP1000A=15mA, TLP1001A=0

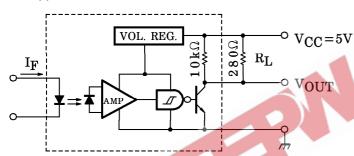
NOTE: SWITCHING TIME TEST CIRCUIT

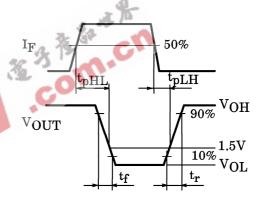
TLP1000A





TLP1001A





PRODUCT INDICATION



MONTHLY PRODUCTION LOT

PRODUCTION MONTH
(JAN.-DEC. ARE INDICATED BY ALPHABETES OF A-L)

— PRODUCTION YEAR (LAST DIGIT OF A.D. IS INDICATED)

STAMP COLOR: SILVER

ABBREVIATION	TYPE		
P1000A	TLP1000A		
P1001A	TLP1001A		

PRECAUTION

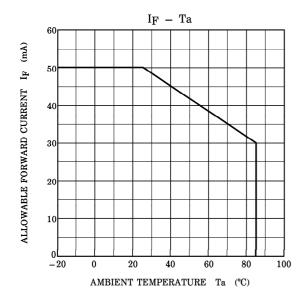
Please be careful of the followings.

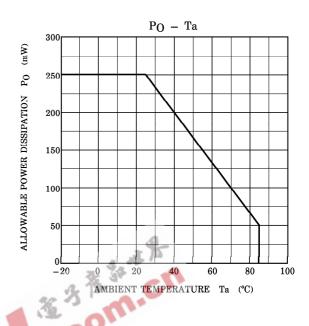
- 1. Soldering should be performed after lead forming.
- 2. If chemicals are used for cleaning, the soldered surface only shall be cleaned with chemicals avoiding the whole cleaning of the package.
- 3. The container is made of polycarbonate. Polycarbonate is usually stable with acid, alcohol, and aliphatic hydrocarbons however, with pertochemicals (such as benzene, toluene, and acetone), alkali, aromatic hydrocarbons, or chloric hydrocarbons, polycarbonate becomes cracked, swollen, or melted. Please take care when chosing a packaging material by referencing the table below.

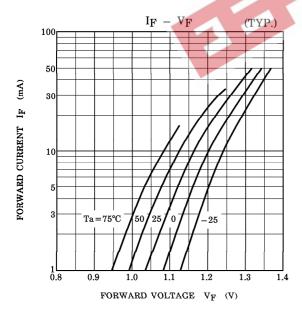
<Chemicals to avoid with polycarbonate>

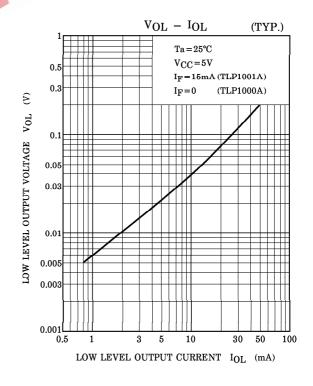
	PHENOMENON	CHEMICALS
A	Little deterioration but staining	• nitric acid (low concentration), hydrogen peroxide, chlorine
В	Cracked, crazed, or swollen	 acetic acid (70% or more) gasoline methyl ethyl ketone, ehtyl acetate, butyl acetate ethyl methacrylate, ethyl ether, MEK acetone, m-amino alcohol, carbon tetrachloride carbon disulfide, trichloroethylene, cresol thinners, oil of turpentine triethanolamine, TCP, TBP
С	Melted { }: Used as solvent.	 concentrated sulfuric acid benzene styrene, acrylonitrile, vinyl acetate ethylenediamine, diethylenediamine [chloroform, methyl chloride, tetrachloromethane, dioxane,] 1, 2-dichloroethane
D	Decomposed	ammonia water other alkali

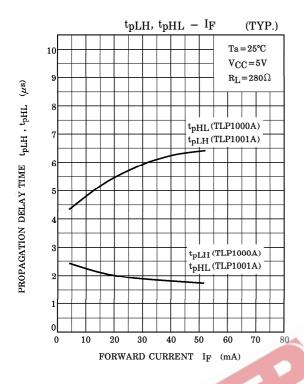
- 4. During $100\mu s$ after turning on VCC, output voltage changes for stabilizing the inner circuit.
- 5. Supply the by-pass condenser up to $0.01\mu F$ between V_{CC} and GND near device to stabilize the power supply line.
- 6. Screw shall be tightened to clamping torque of 0.59N·m.

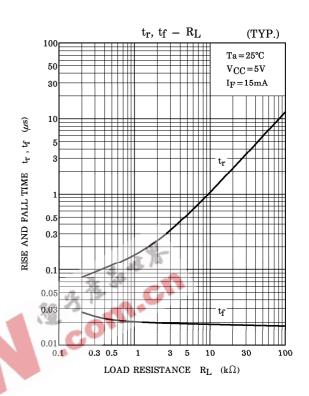


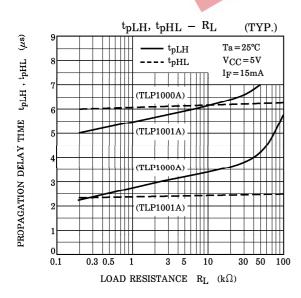


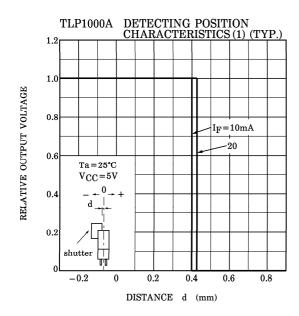


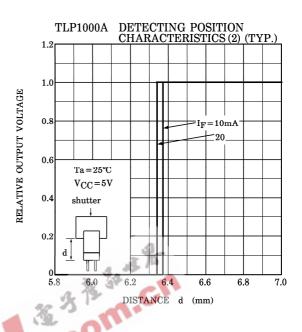


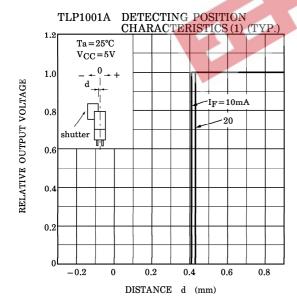


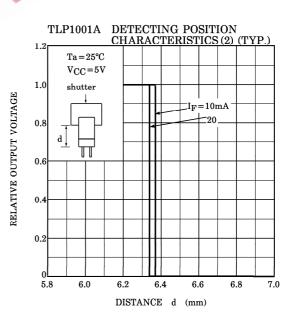












POSITIONING OF SHUTTER AND DEVICE

To operate correctly, make sure that the shutter and the device are positioned as shown in the figure below.

The shit pitch of the shutter must be set wider than the slit width of the device. Determine the width taking the switching time into consideration.

